

1618-35

35 Watt - 28 Volts, Class C Microwave 1600 - 1800 MHz

GENERAL DESCRIPTION

The 1618-35 is a COMMON BASE transistor capable of providing 35 Watts of Class C, RF output power over the band 1600-1800 MHz. This transistor is designed for Microwave Broadband Class C amplifier applications. It includes Input and Output prematching and utilizes Gold metalization and diffused ballasting to provide high reliability and supreme ruggedness. The transistor uses a fully hermetic High Temperature Solder sealed package.

ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation @ 25°C 135 Watts

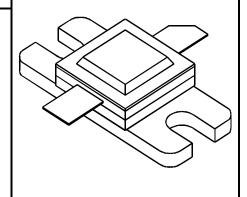
Maximum Voltage and Current

BVcesCollector to Emitter Voltage45 VoltsBVeboEmitter to Base Voltage3.5 VoltsIcCollector Current12 A

Maximum Temperatures

Storage Temperature $-65 \text{ to} + 200^{\circ}\text{C}$ Operating Junction Temperature $+200^{\circ}\text{C}$

CASE OUTLINE 55AW, STYLE 1



ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Pout Pin Pg η _c VSWR ₁	Power Out Power Input Power Gain Collector Efficiency Load Mismatch Tolerance	F = 1600-1800 MHz Vcb = 28 Volts Pin = 7 Watts As Above F = 1.1 GHz, Pin = 7 W	35	7.0 40	7 10:1	Watt Watt dB %

BVces BVebo H _{FE} Cob	Collector to Emitter Breakdown Emitter to Base Breakdown Current Gain Output Capacitance Thermal Resistance	Ic = 20 mA Ie = 15 mA Vce = 5 V, Ic = 1 A F = 1 MHz, Vcb = 28V	45 3.5 10		100	Volts Volts pF °C/W
--	---	---	-----------------	--	-----	------------------------------

Issue A, July 1997

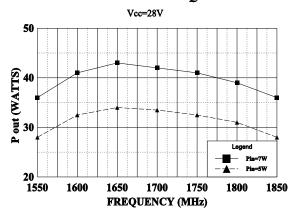
GHz TECHNOLOGY INC. RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE. GHZ RECOMMENDS THAT BEFORE THE PRODUCT(S) DESCRIBED HEREIN ARE WRITTEN INTO SPECIFICATIONS, OR USED IN CRITICAL APPLICATIONS, THAT THE PERFORMANCE CHARACTERISTICS BE VERIFIED BY CONTACTING THE FACTORY.

GHz Technology Inc. 3000 Oakmead Village Drive, Santa Clara, CA 95051-0808 Tel. 408 / 986-8031 Fax 408 / 986-8120

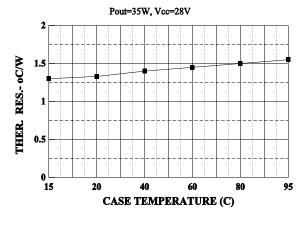




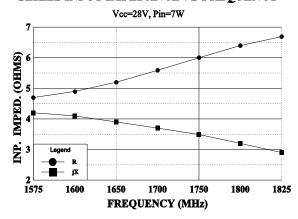
POWER OUTPUT vs FREQUENCY



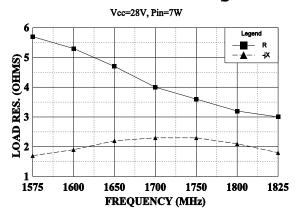
THERMAL RESISTANCE vs CASE TEMPERATURE



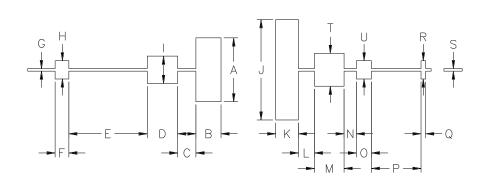
SERIES INPUT IMPEDANCE VS FREQUENCY



SERIES LOAD IMPEDANCE vs FREQUENCY

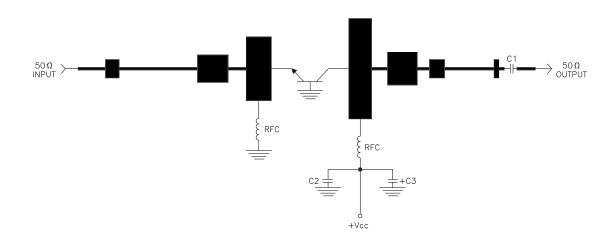






HES
00
75
0C
35
50
50
28
00
00
00
50
75
25
35
65
45
50
00
28
50
00

1618-35 TEST AMPLIFIER f = 1.6-1.8 GHz



= Microstrip on 0.010" Duroid, Er=2.3 C1,C2 = 82 pf CHIP CAP C3 = 1μ fd @ 35 Volts



CAGE	DWG NO.			REV
0PJR2		1618 - 35		A
	SCALE	1/1	SHEET	